TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (Ultra-High-Speed U-MOSIII)

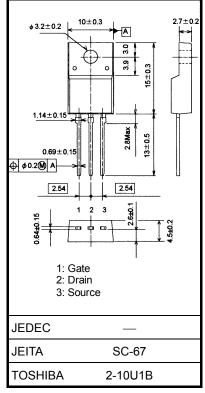
TK40A10J1

Switching Regulator Applications

- Small gate charge: Q_g = 76nC (typ.)
- Low drain-source ON-resistance: $R_{DS (ON)}$ = 11.5 m Ω (typ.)
- High forward transfer admittance: $|Y_{fs}| = 90 \text{ S}$
- Low leakage current: I_{DSS} = 10 μ A (max) (V_{DS} = 100 V)
- Enhancement mode: V_{th} = 1.1 to 2.3 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V _{DSS}	100	V	
Drain-gate voltage (F	R _{GS} = 20 kΩ)	V _{DGR}	100	V	
Gate-source voltage		V _{GSS}	±20	V	
Drain current	DC (Note 1)	I _D	40	А	
	Pulse (Note 1)	I _{DP}	160	A	
Drain power dissipat	ion (Tc = 25°C)	PD	40	W	
Single pulse avalanche energy (Note 2)		E _{AS}	202	mJ	
Avalanche current		I _{AR}	40	А	
Repetitive avalanche	energy (Note 3)	E _{AR}	2.4	mJ	
Channel temperature	9	T _{ch}	150	°C	
Storage temperature	range	T _{stg}	-55 to 150	°C	



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	3.125	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W

Internal Connection



Note 1: Ensure that the channel and lead temperatures do not exceed 150°C.

Note 2: V_{DD} = 25 V, T_{ch} = 25°C, L = 200 $\mu H,~I_{AR}$ = 40 A , R_G = 1 Ω

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic- sensitive device. Handle with care.

Unit: mm

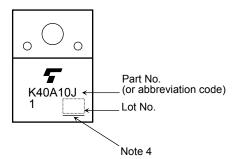
Electrical Characteristics (Ta = 25°C)

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I _{GSS}	$V_{GS}=\pm 16~V,~V_{DS}=0~V$		_	±10	μA
Drain cut-OFF cu	rrent	I _{DSS}	$V_{DS} = 100 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$		_	10	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10$ mA, $V_{GS} = 0$ V	100		_	v
		V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	60	_	_	
Gate threshold vo	oltage	V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	1.1	—	2.3	V
Drain-source ON resistance		R _{DS (ON)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	_	13	17	mΩ
			$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$		11.5	15	
Forward transfer	admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	45	90	_	S
Input capacitance		C _{iss}	V _{DS} = 10V, V _{GS} = 0 V, f = 1 MHz	_	4300	_	pF
Reverse transfer capacitance		C _{rss}			230		
Output capacitance		C _{oss}			790		
Switching time	Rise time	tr	$V_{GS}^{10 V} \downarrow I_{D} = 20 A$ $V_{GS}^{0 V} \downarrow I_{W} = 10 \mu s$ $I_{D} = 20 A$ $V_{OUT}^{0 V} \downarrow I_{W} = 2.5\Omega$ $V_{DD} \simeq 50 V$	_	14	_	ns
	Turn-ON time	t _{on}		_	22		
	Fall time	t _f		_	24	_	
	Turn-OFF time	t _{off}		_	115	_	
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD}\simeq 80~V,~V_{GS}=5~V,~I_{D}=40A$		44	_	
			$V_{DD}\simeq 80~V,~V_{GS}=10~V,~I_{D}=40A$	_	76	_	
Gate-source charge 1		Q _{gs1}		_	11	_	nC
Gate-drain ("miller") charge		Q _{gd}	$V_{DD}\simeq 80~V,~V_{GS}=10~V,~I_{D}=40A$	_	21	—	
Gate switch charge		Q _{sw}		—	24	—	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	_	_	40	А
Pulse drain reverse current (Note 1)	I _{DRP}	—	_	_	160	А
Forward voltage (diode)	V _{DSF}	I _{DR} = 40 A, V _{GS} = 0 V	_	-0.9	-1.2	V
Reverse recovery time	t _{rr}	$I_{DR} = 40 \text{ A}, V_{GS} = 0 \text{ V},$	_	55	_	ns
Reverse recovery charge	Q _{rr}	dI _{DR} /dt = 50 A/µs	_	63	_	nC

Marking

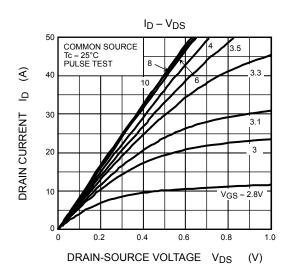


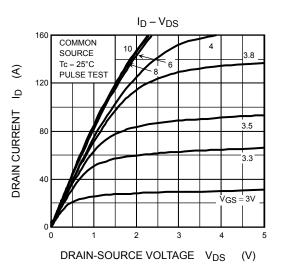
Note 4: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV

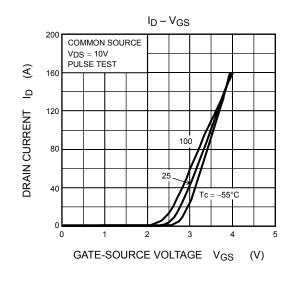
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

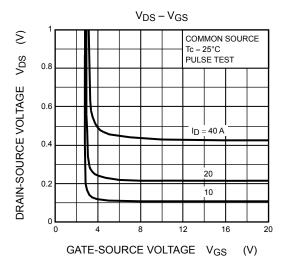
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

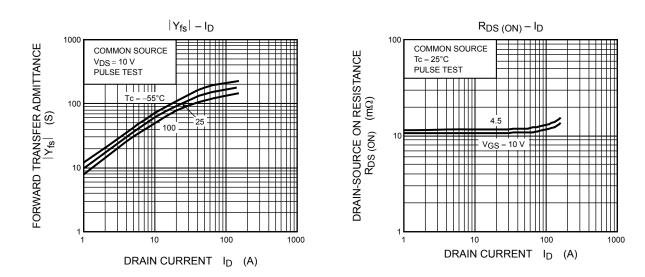
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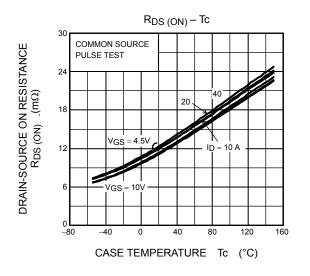


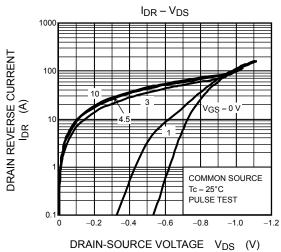


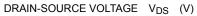


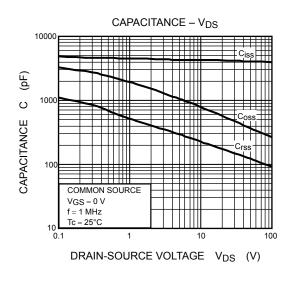
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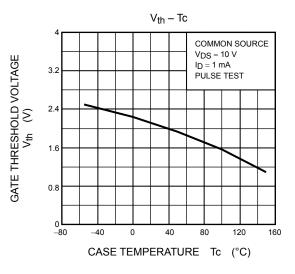
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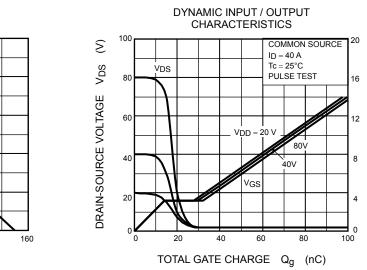


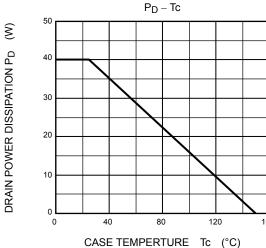








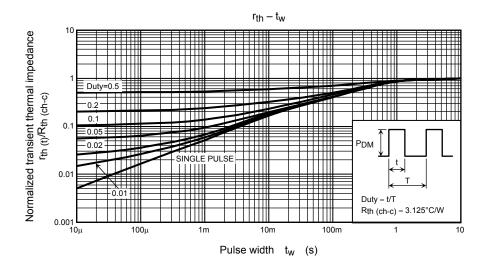


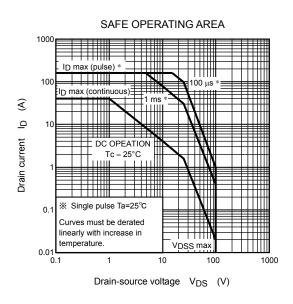


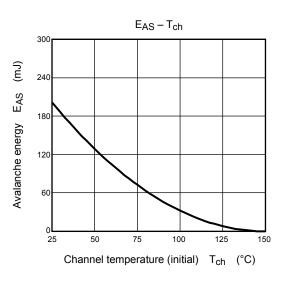
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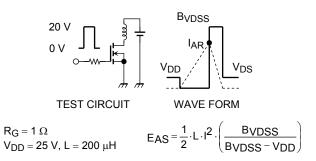
Vgs

GATE-SOURCE VOLTAGE









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